Docket No.: 1016-017

the specification of which

DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare that:

My residence, post office address, and citizenship are as stated below next to my name,

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter claimed and for which a patent is sought on the invention entitled:

VIA/LINE INDUCTOR ON SEMICONDUCTOR MATERIAL

the specification of	WIIICII								
is attached here	to								
was filed on as Application Serial No and was amended on I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.									
119(a)-(d) or Secti certificate, or Secti least one country of below any foreign	ion 365(b) of an on 365(a) of any other than the Un application for p	nefits under Title 35, United ny foreign application(s) for PCT international application nited States, listed below are patent or inventor's certification och priority is claimed:	or patent or inventor's on which designated at nd have also identified						
Prior Foreign App	olication(s):								
Number Number	Country	Day/Month/Year filed	Priority Claimed <u>Yes</u> <u>No</u>						
I hereby claim the bapplication(s) listed		USC 119(e) of any United Sta	ates provisional						
Prior Provisional	Application(s):								
Application Numb	<u>ber</u> <u>Filing</u>	g Date							
States application(s	s), or Section 3650	e 35, United States Code, Sec (c) of any PCT international insofar as the subject matter	application designating						

this application is not disclosed in the prior United States or PCT international application in the manner provided by the first paragraph of Title 35, United States Code, Section 112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, Section 1.56 which occurred between the

Docket No.: 1016-017

filing date of the prior application and the national or PCT international filing date of this application:

Prior U.S. Application(s):

Serial No.

Filing Date

Status: Patented, Pending, Abandoned

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

I hereby revoke any previous Powers of Attorney and appoint the following attorney(s) and/or agent(s), each said individual being a member or associate of The Law Offices of Mikio Ishimaru or being employed by Chartered Semiconductor Manufacturing Ltd.:

Mikio Ishimaru

Reg. No. 27,449

for so long as they remain with such law offices or company with full power of substitution and revocation, to prosecute this application and to transact in connection therewith all business in the U.S. Patent and Trademark Office and before competent International Authorities; said appointment to be to the exclusion of myself and my other attorney(s); and all future correspondence should be addressed to:

Mikio Ishimaru The Law Offices of Mikio Ishimaru 1110 Sunnyvale-Saratoga Rd., Suite Al Sunnyvale, California 94087

Inventor's signature:_		Date:
Full name of sole or fi	rst inventor: Zhang JIONG	
Citizenship:	People's Republic of China	
Residence Address:	Bukit Batok West Ave. 4 Blk 409 #10-162	
Post Office Address:	Singapore 650409 c/o Chartered Semiconductor Mfg. Ltd.	
1 ost office riddress.	No. 60 Woodlands Industrial Park D Street 2	

Singapore 738406 Republic of Singapore Docket No.: 1016-017

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Inventor's signature: _		_Date: _		5,	200	f
Full name of joint inv	entor: Yi Min WANG					
Citizenship:	People's Republic of China					
Residence Address:	Bukit Batok West Ave. 4 Blk 409 #10-162 Singapore 650409					
Post Office Address:	c/o Chartered Semiconductor Mfg. Ltd. No. 60 Woodlands Industrial Park D Street 2 Singapore 738406 Republic of Singapore					
Inventor's signature:_	7. · C		1-2	2	ĊĊ	i
	entor: Shao-fu Sanford CHU					
Citizenship:	<u>U.S.A.</u>					
Residence Address:	9 Beechwood Grove Singapore 727927					
Post Office Address:	c/o Chartered Semiconductor Mfg. Ltd. No. 60 Woodlands Industrial Park D Street 2 Singapore 738406 Republic of Singapore					